SS32 THRU SS3A

SCHOTTKY BARRIER RECTIFIERS Reverse Voltage - 20 to 100 V Forward Current - 3 A

Features

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- · Metal silicon junction, majority carrier conduction
- · For surface mount applications
- · Low power loss, high efficiency
- High current capability, low forward voltage drop.
- Low profile package
- · Built-in strain relief, ideal for automated placement
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

Mechanical Data

- Case: SMB (DO-214AA), molded plastic body
- Terminals: Solder plated, solderable per MIL-STD-750, method 2026
- · Polarity: Color band denotes cathode end

Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, resistive or inductive load. For capactive load, derate by 20 %.

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Parameter	Symbols	SS32	SS33	SS34	SS35	SS36	SS38	SS3A	Units
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	20	30	40	50	60	80	100	V
Maximum RMS Voltage	V _{RMS}	14	21	28	35	42	57	71	V
Maximum DC Blocking Voltage	V_{DC}	20	30	40	50	60	80	100	V
Maximum Average Forward Rectified Current at 0.375"(9.5 mm) Lead Length	I _{F(AV)}	3							А
Peak Forward Surge Current 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	80						A	
Maximum Instantaneous Forward Voltage at 3 A	V _F	0.55		0.1	0.75 0.		.85	V	
Maximum Reverse Current at Rated at $T_a = 25 ^{\circ}C$	I _R	1.5							mA
DC Blocking at Voltage at $T_a = 100 \text{ °C}$	IR		20		10				IIIA
Typical Junction Capacitance ¹⁾	C_j		250 160					pF	
Typical Thermal Resistance ²⁾	$R_{ heta JA}$ $R_{ heta JL}$		55 17						°C/W
Operating Junction Temperature Range	Tj	- 6	- 65 to + 125 - 65 to + 150						°C
Storage Temperature Range	T _{stg}	- 65 to + 150						°C	

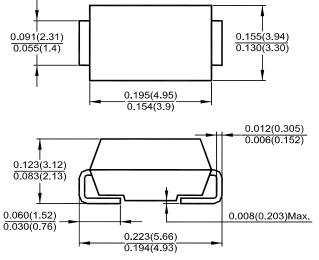
¹⁾ Measured at 1 MHz and reverse voltage of 4 V

²⁾ P.C.B. mounted 0.55 X 0.55" (14 X 14 mm) copper pad areas.



SEMTECH ELECTRONICS LTD.

Subsidiary of Sino-Tech International (BVI) Limited



SMB (DO-214AA)

Dimensions in inches and (millimeters)

MOODY

S-OHSAS 18001 : 2007 IECQ QC 08000 Certificate No. 7116 Certime No. RCHSPH-145

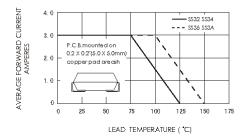
MOODY

ISO 9001 : 2008 Certificate No. 0506000

MOODY

MOODY

2009 ISO14001 5103 Certificate I FIG.1-FORWARD CURRENT DERATING CURVE





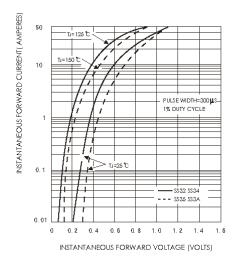


FIG.5-TYPICAL JUNCTION CAPACITANCE

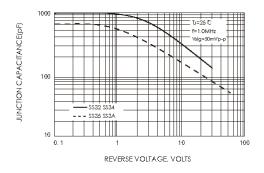
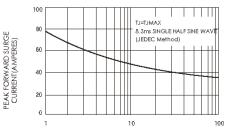
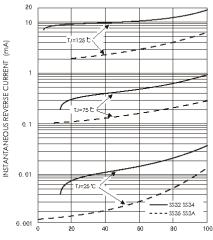


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



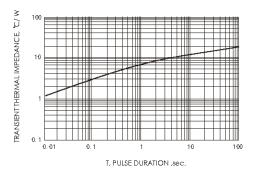
NUMBER OF CYCLES AT 60Hz

FIG.4-TYPICAL REVERSE CHARACTERISTICS



PERCENT OF RATED PEAK REVERSE VOLTAGE%

FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE









Dated: 22/03/2012 J Rev: 02